

MMIQ-30120HCH-2

GaAs MMIC mmWave Differential IF IQ Mixer

DEVICE OVERVIEW

General Description

The MMIQ-30120H is a high linearity, passive GaAs MMIC IQ mixer. This is an ultra-broadband mixer spanning 30 to 120 GHz on the RF and LO ports with an IF from DC to 30 GHz. With a typical image rejection of 27dBc from the V through W band, this mixer is an ideal candidate for mmWave I/Q frequency conversion. Both wire bondable die and connectorized modules are available.



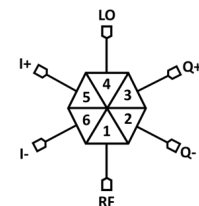
Features

RF/LO Frequency Range:
 30 - 120 GHz
 IF Frequency Range:
 DC - 30 GHz
 I+Q Conversion Loss: 8.5 dB
 Image Rejection: 27 dBc

Applications

- mmWave Frequency Conversion
- Differential IF, Single Side Band & Image Rejection Mixing
- IQ Modulation / Demodulation
- Vector Signal Modulation and Demodulation
- Band Shifting

Functional Block Diagram



Part Ordering Options

Part Number	Description	Package	Packing Size	Green Status	Product Lifecycle	Export Classification
<u>MMIQ-30120HM</u>	GaAs MMIC mmWave Differential IF IQ Mixer	M	-	RoHS	Released	EAR99
MMIQ-30120HCH-2	GaAs MMIC mmWave Differential IF IQ Mixer	CH	-	RoHS RoHS	Released	EAR99

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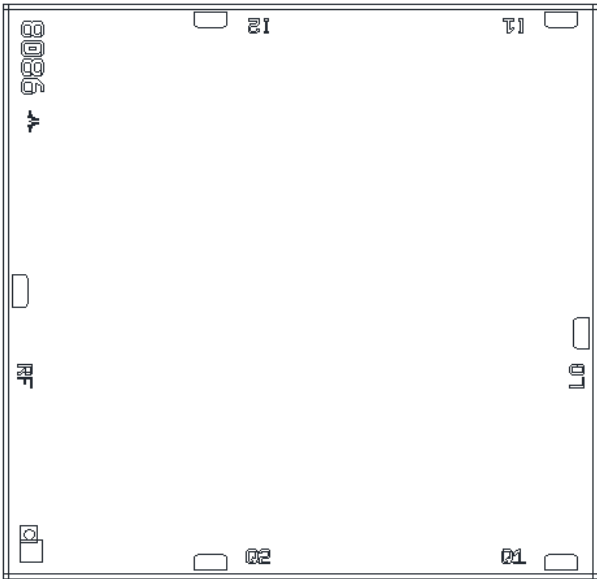
Revision History

Revision Code	Revision Date	Comment
-	2023-01-01	Datasheet Pre-Release

Port Configuration and Functions

Port Diagram

A top-down view of the MMIQ-30120H's CH-2 package outline drawing is shown below. The mixer may be operated as either a downconverter or an upconverter. Use of the RF or I/Q as the input or output port will depend on the application.



Port Functions

Port	Function	Description	Equivalent Circuit for Package
GND	Ground	CH package ground path is taken through the substrate.	GND 
Port 1 / RF	RF Input / Output	Port 1 is DC open for the CH and M packages.	P1 
Port 2 / Q2	Q Input / Output	Port 2 is DC open for the CH and M packages	P2 
Port 3 / Q1	Q+ Input/Output	Port 3 is DC open for the CH and M packages.	P3 
Port 4 / LO	LO Input/Output	Port 4 is DC open for the CH and M packages.	P4 
Port 5 / I1	I+ Input/Output	Port 5 is DC open for the CH and M packages.	P5 
Port 6 / I2	I- Input/Output	Port 6 is DC open for the CH and M packages.	P6 

Specifications

Absolute Maximum Ratings

The Absolute Maximum Ratings indicate limits beyond which damage may occur to the device. If these limits are exceeded, the device may be inoperable or have a reduced lifetime.

Parameter	Maximum Rating	Unit
Maximum Operating Temperature	100	°C
Maximum Storage Temperature	125	°C
Minimum Operating Temperature	-55	°C
Minimum Storage Temperature	-65	°C
Power Handling, at any Port	25	dBm

Package Information

Parameter	Details	Rating
ESD	250 to < 500 Volts	HBM Class 1A
Dimensions	-	2.71x2.80 mm

Recommended Operating Conditions

The Recommended Operating Conditions indicate the limits, inside which the device should be operated, to guarantee the performance given in Electrical Specifications. Operating outside these limits may not necessarily cause damage to the device, but the performance may degrade outside the limits of the electrical specifications. For limits, above which damage may occur, see Absolute Maximum Ratings.

Parameter	Min	Nominal	Max	Unit
Ambient Temperature	-55	25	100	°C
LO Input Power	14	17	21	dBm

Sequencing Requirements

There is no requirement to apply power to the ports in a specific order. However, it is recommended to provide a 50Ω termination to each port before applying power. This is a passive diode mixer that requires no DC bias.

Electrical Specifications

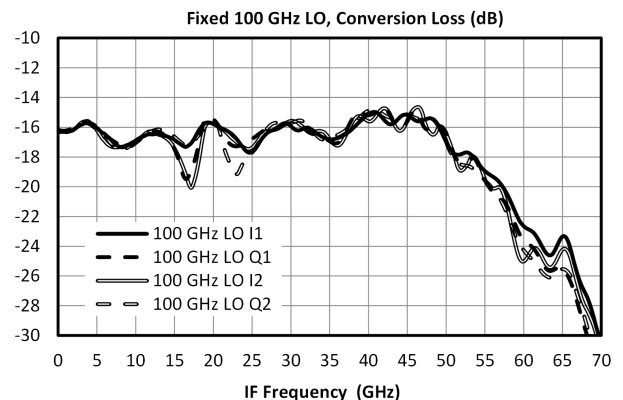
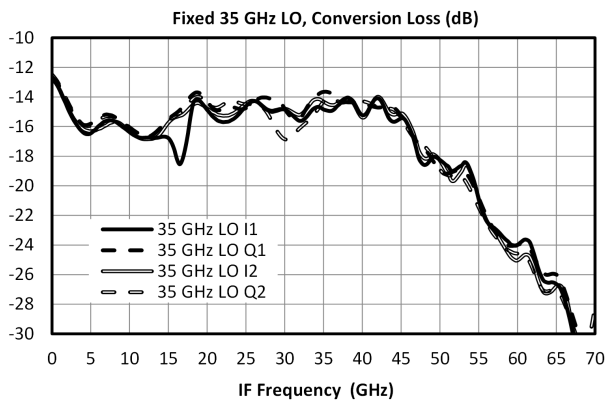
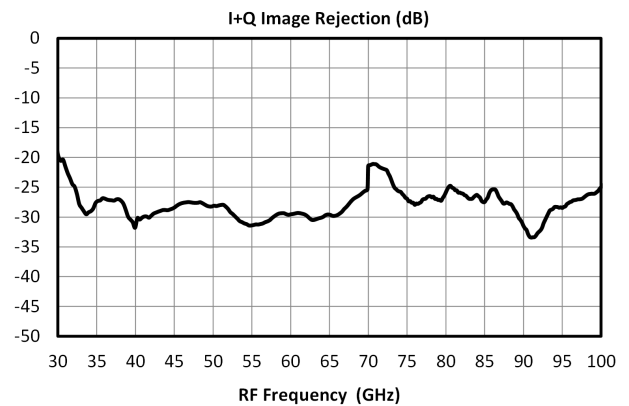
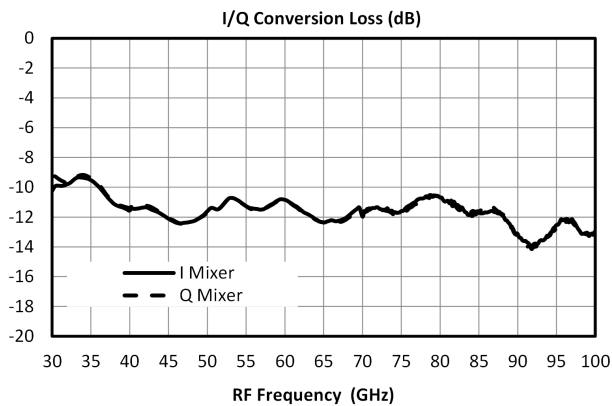
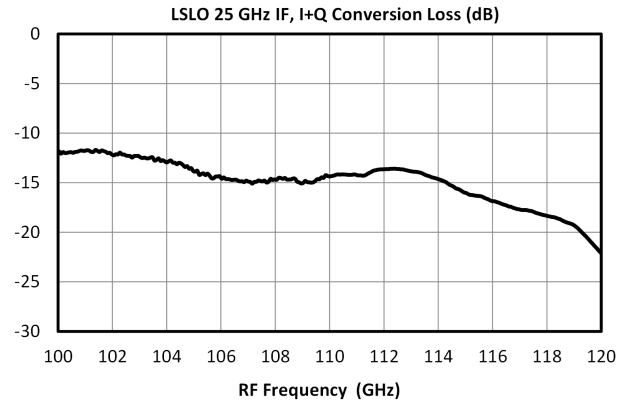
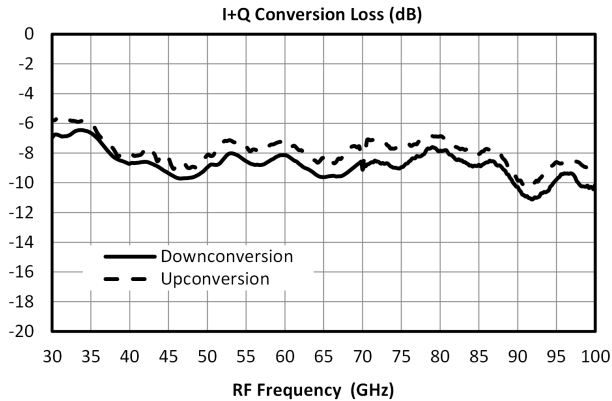
The electrical specifications apply at $T_A = +25^\circ\text{C}$ in a 50Ω system. Typical data shown is for a down conversion application with a sine wave LO input. Min and Max limits apply only to our connectorized units and are guaranteed at $T_A = +25^\circ\text{C}$

Parameter	Test Conditions	Minimum Frequency (GHz)	Maximum Frequency (GHz)	Min	Typ	Max	Unit
RF Frequency Range	-	-	-	30	-	120	GHz
LO Frequency Range	-	-	-	30	-	120	GHz
Conversion Loss	RF/LO = 30 – 120 GHz I+Q = 0.1 GHz	30	120	-	8.5	-	dB
Image Rejection ¹	RF/LO = 30 - 120 GHz I+Q = 0.1 GHz	30	120	-	27	-	dBc
IF Frequency Range	-	-	-	0	-	30	GHz
I/Q Amplitude Balance	RF/LO = 30 - 120 GHz I+Q = 0.1 GHz	30	120	-	1.9	-	dB
I/Q Phase Balance	RF/LO = 30 - 120 GHz I+Q = 0.1 GHz	30	120	-	2.7	-	°
Isolation, LO to RF	RF/LO = 30 - 120 GHz I+Q = 0.1 GHz	30	120	-	40	-	dB

^[1] Image Rejection and Single sideband performance plots are defined by the upper sideband (USB) or lower sideband (LSB) with respect to the LO signal. Plots are defined by which sideband is selected by the external IF quadrature hybrid.

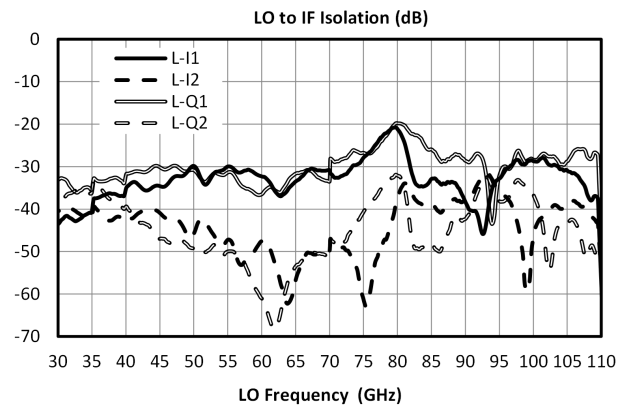
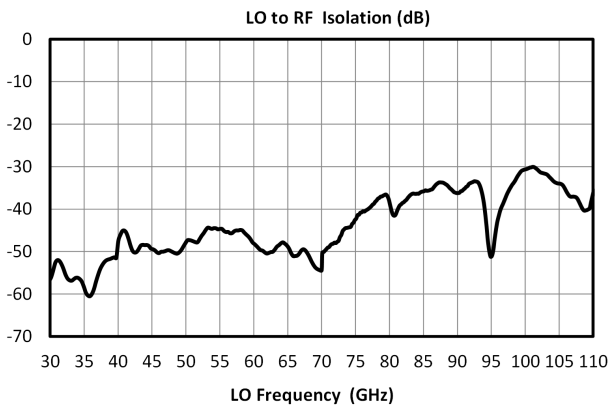
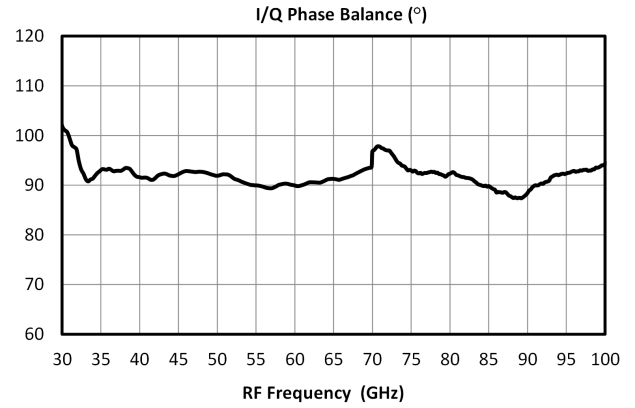
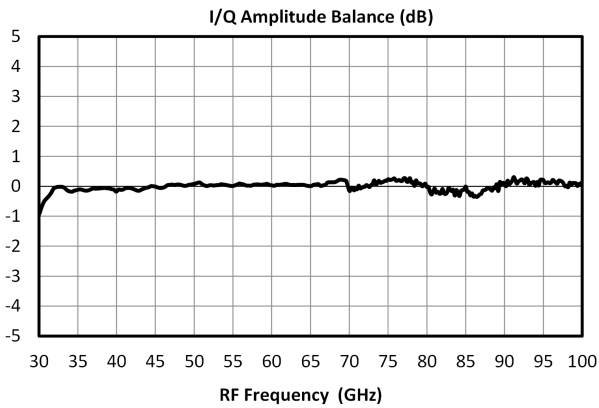
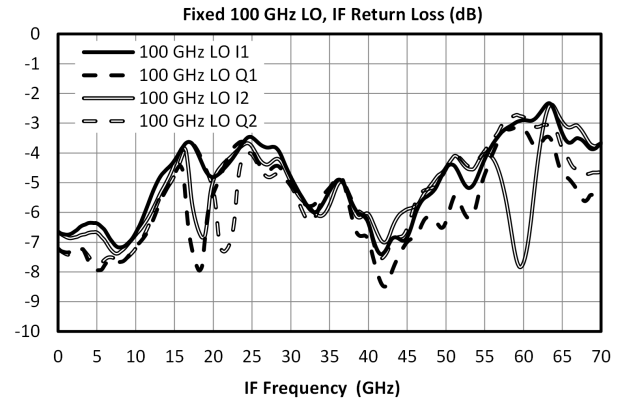
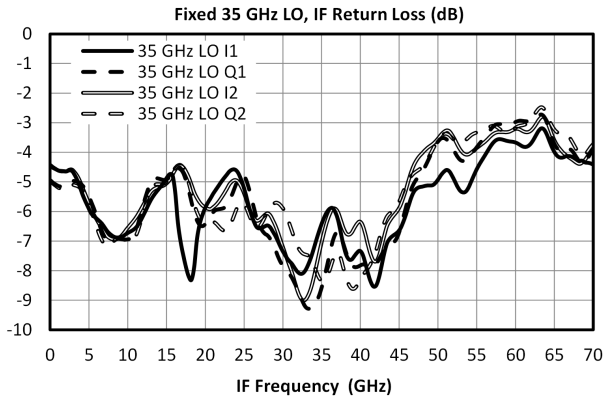
Typical Performance Plots

Unless stated otherwise, all measurements were conducted with a single I1/I2 and a single Q1/Q2. Differential IFs were not recombined through a balun.



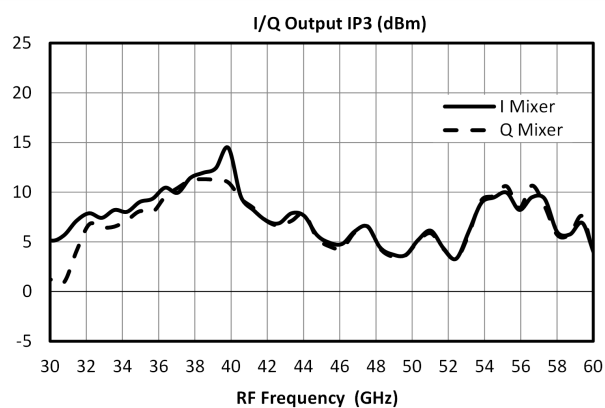
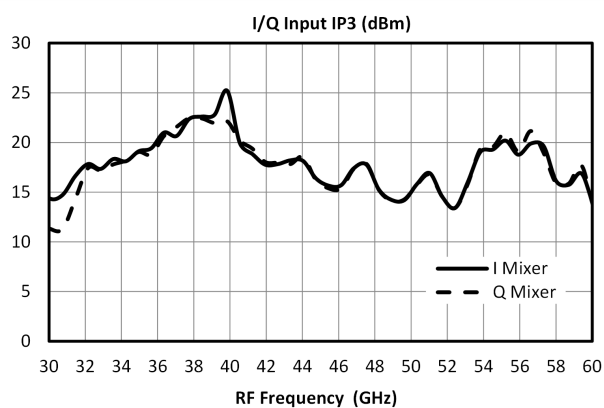
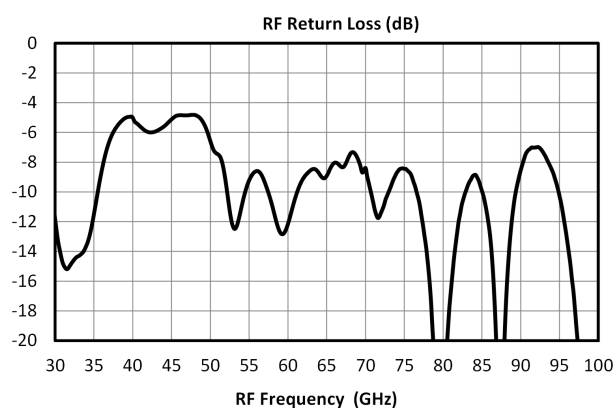
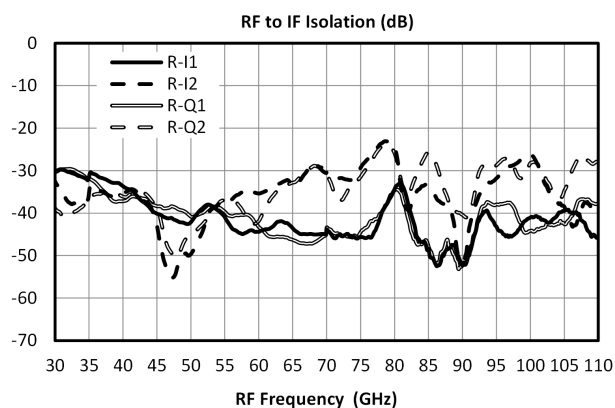
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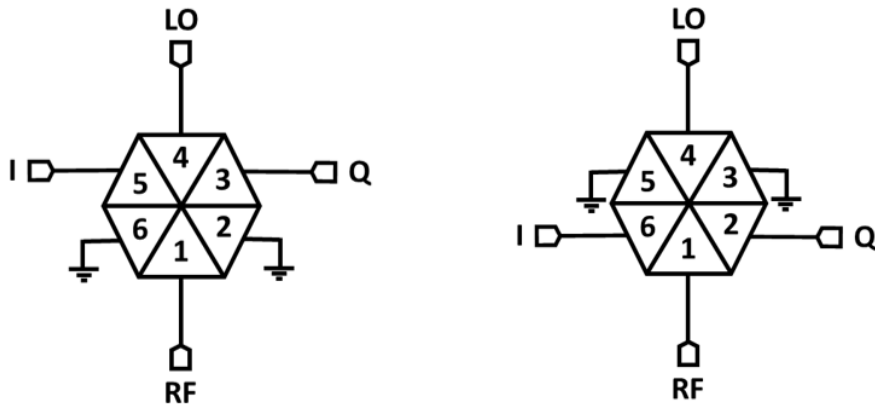
GaAs MMIC mmWave Differential IF IQ Mixer



Application Information

Differential IF IQ Mixer Application

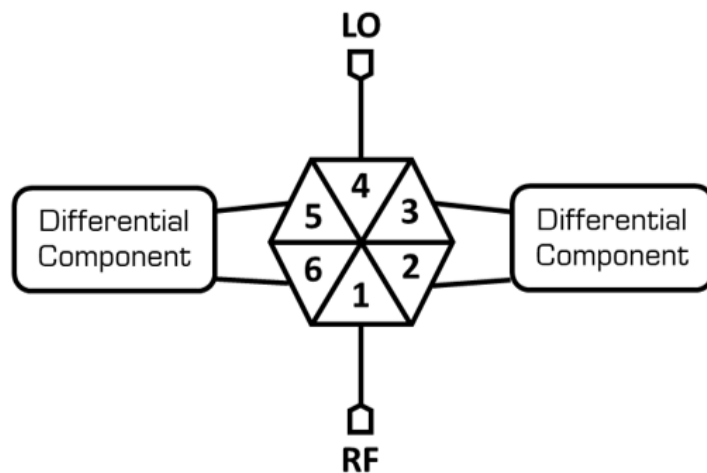
Single Ended Operation:



Choose one IF (I+ and Q+ or I- and Q-) and short the unused IF ports to ground

Single ended operation allows for use of a DC IF signal

Differential IF Operation:



The mixer in its standard configuration is set up for use with differential IFs

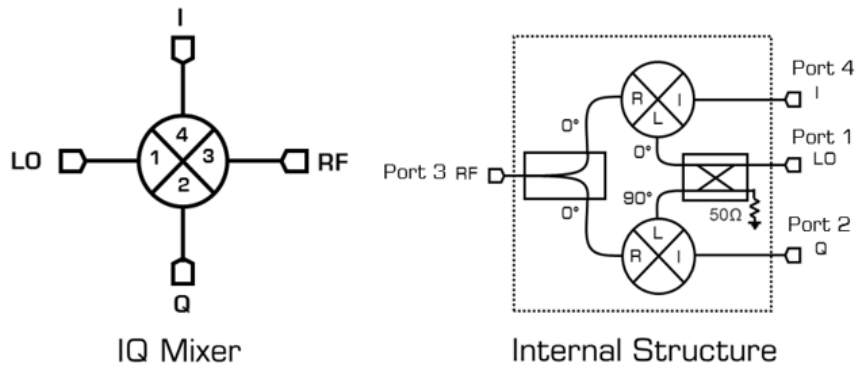
Each IF port is 50Ω single ended/100Ω differential between I+/I- and Q+/Q-

Differential operation allows for common mode cancellation allowing one to run an ADC/DAC in differential mode

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Application Circuit



Application Circuit Description

The MMIQ-30120H belongs to Marki Microwave's MMIQ family of mixers. The MMIQ product line consists of passive GaAs MMIC mixers designed and fabricated with GaAs Schottky diodes. MMIQ mixers offer excellent amplitude and phase balance due to its on-chip LO quadrature hybrid. Up to 27 dB of image rejection (i.e., single sideband suppression) can be obtained by using the MMIQ-30120H as an image rejection or single sideband mixer.

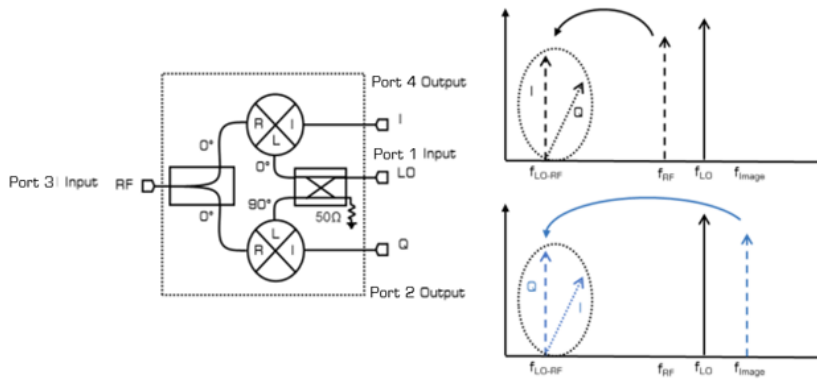
Support for the Ka through mmWave bands are offered by the ultra-broadband performance of the mixer's RF and LO ports (ports 1 and 4). Traditional use of this mixer to do image reject or single sideband mixing is available with an external IF quadrature hybrid. The MMIQ-30120H is also suitable for use as a Vector Modulator through DC bias of the I and Q ports (one must configure the IQ mixer for DC IF operation as shown in Differential IF IQ Mixer Application.)

The RF port and the LO port support a 30-120 GHz signal. The I and Q ports support a DC-30 GHz signal. A signal may be input into any port of the mixer which supports that signal's frequency. This is the basis of using the mixer as a band shifter.

For a given LO power within the recommended operating range, the RF (in the case of a down conversion) or IF (in the case of an up conversion) input power should be below the input 1 dB compression point to avoid signal distortion. The input 1 dB compression point will vary across the mixer's operating bandwidth and with LO input power. Careful characterization is required for optimal performance for each application. There is no minimum small signal input power required for operation. Excessive RF/IF input power increases non-desired spurious output power and degrades the fundamental conversion loss. Excessive LO input power can also cause this effect. The table below describes how to use an IQ mixer and quad hybrid to select a single sideband.

Up Conversion		
Hybrid Port	Mixer Port	Sideband Selected
0	I	Lower Sideband
90	Q	
90	I	Upper Sideband
0	Q	
Down Conversion		
Hybrid Port	Mixer Port	Sideband Selected
0	I	Upper Sideband
90	Q	
90	I	Lower Sideband
0	Q	

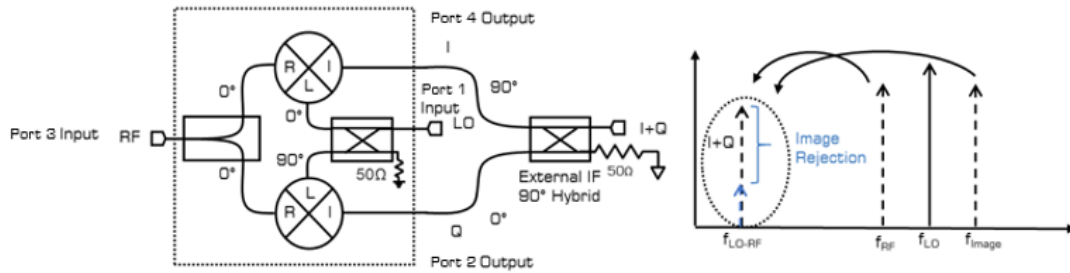
Down-Converter



A down converter is a mixer application which takes a high frequency small signal RF input, and a high frequency large signal LO input and mixes the signals together to produce a low frequency IF output. The fundamental $1RF \times 1LO$ outputs present at the IF port are the f_{LO-RF} and f_{LO+RF} tones. The desired output in a down conversion is typically the f_{LO-RF} term. An image frequency at $f_{Image} = f_{LO+RF}$ will also down convert to the f_{LO-RF} frequency. The above illustration shows the relative location of the image frequency for a highside LO, or the frequency plan for which $f_{LO} > f_{RF}$.

To use the IQ mixer as a down converter, input a high frequency small signal RF input, a high frequency large signal LO input, and pull the low frequency IF output. The IF ports will output the IF signals I and Q. I and Q IF outputs will be at the same frequency but 90° out of phase (i.e., I and Q are in quadrature). If only a single IF output is desired, terminate either the I or Q ports with a wideband 50Ω load.

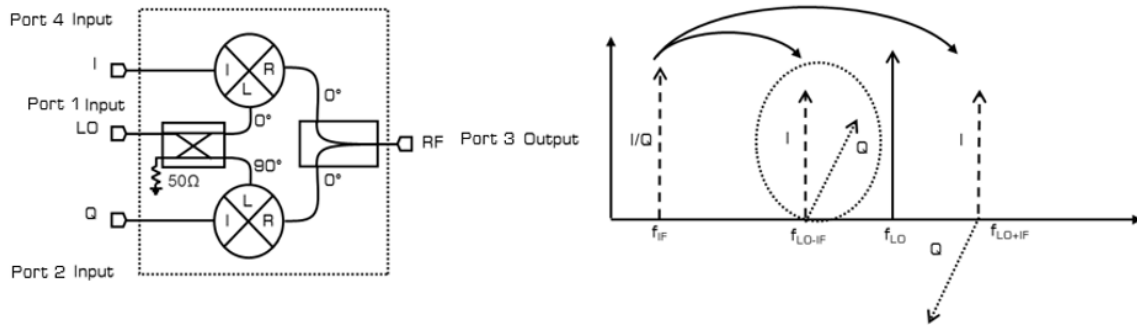
Image Reject Down-Converter



An image reject mixer is a mixer which rejects the down converted image frequency from the IF output. Image reject mixers are constructed using an external quadrature hybrid attached to the I and Q (i.e., IF) output ports. Using the external IF quadrature hybrid, one can select the whether the upper sideband or lower sideband signal is suppressed with respect to the LO signal.

To use the IQ mixer as an image reject mixer, input the high frequency small signal RF into and a high frequency large signal LO input into. Take the combined I+Q down converted signal through the IF quadrature hybrid. Select the upper sideband (i.e., suppress the lower sideband) by connecting the I port to the 0° port of the IF quadrature hybrid and attach the Q port to the 90° port of the IF quadrature hybrid. Select the lower sideband (i.e., suppress the upper sideband) by attaching the I port to the 90° port of the IF quadrature hybrid and attach the Q port to the 0° port of the IF quadrature hybrid.

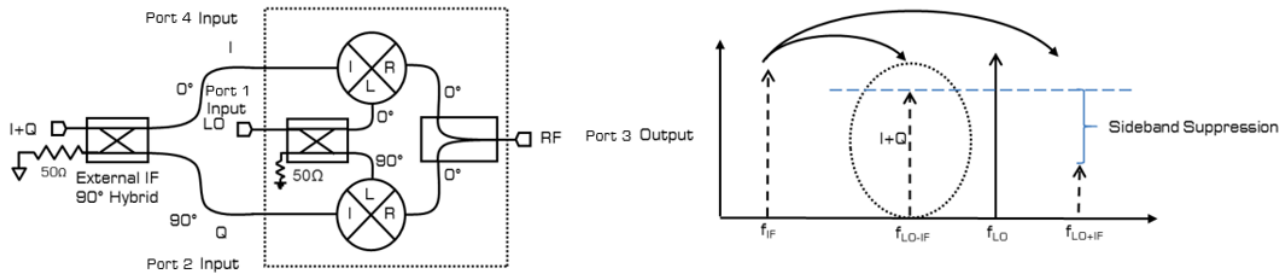
Up-Converter



An up converter is a mixer application which takes a low frequency small signal IF input, and a high frequency large signal LO input and mixes the signal together to produce a high frequency RF output. The fundamental $1f_{IF} \times 1f_{LO}$ outputs present at the RF port are the f_{LO-IF} and f_{LO+IF} tones. An up conversion can select either the f_{LO-IF} or the f_{LO+IF} tones. The above illustration shows both up converted sidebands with either an I or Q port input signal.

To use the IQ mixer as an up converter, input a low frequency small signal IF input, a high frequency large signal LO input, and pull the high frequency RF output. Input into the Q port will result in a up converted signal that is 90° out of phase with the up converted I port input signal. If only a single IF input is desired, terminate either the I or Q ports with a wideband 50Ω load.

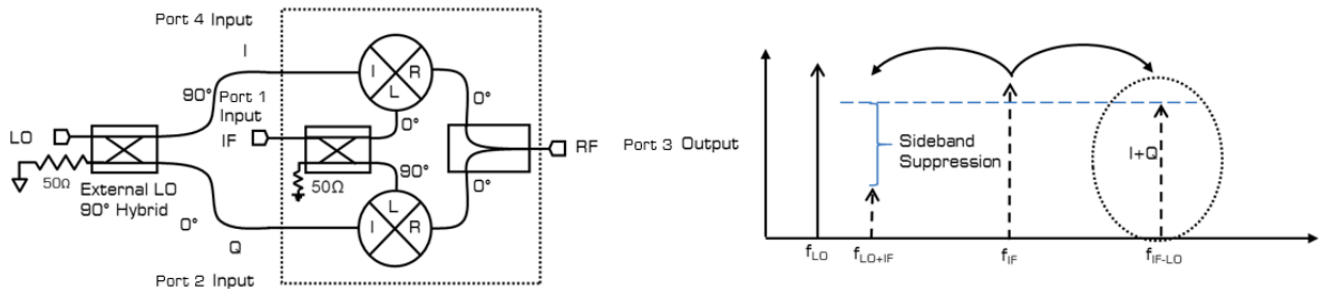
Single Sideband Up-Converter



A single sideband mixer is a mixer which suppresses the up converted image frequency from the RF output. Single sideband mixers are constructed using an external quadrature hybrid attached to the I and Q (i.e., IF) input ports. Using an external IF quadrature hybrid, one can select whether the upper sideband of the lower sideband signal is suppressed with respect to the LO signal.

To use the IQ mixer as a single sideband mixer, input the low frequency small signal I+Q IF signal into the IF quadrature hybrid. The IF quadrature hybrid is attached to the I and Q ports of the IQ mixer. Input the high frequency large signal LO input and take the up converted high frequency RF signal. Select the upper sideband (i.e., suppress the lower sideband) by attaching the I port to the 90° port of the IF quadrature hybrid and attach the Q port to the 0° port of the IF quadrature hybrid. Select the lower sideband (i.e., suppress the upper sideband) by attaching the I port to the 0° port of the IF quadrature hybrid and attach the Q port to the 90° port of the IF quadrature hybrid.

Band Shifter



A band shifter is an unusual application for a mixer. Band shifters take an IF signal and shift it to a different band, generally to either avoid interference or for rebroadcast at a different frequency. For cases in which the desired band shift cannot be employed by using a standard up or down conversion scheme, an exotic input scheme is required.

A passive diode mixer is reciprocal on all ports. The RF port supports a 30-120GHz signal. Port 1, the LO port, supports a 30-120GHz signal. The IF ports support a DC-30GHz signal. 2 signals input into any combination of the RF, LO, or IF, will result in an output signal at the remaining port. In addition, an output signal will be present at both input ports. By using the IF port, as a large signal input port, low frequency LO applications can be supported.

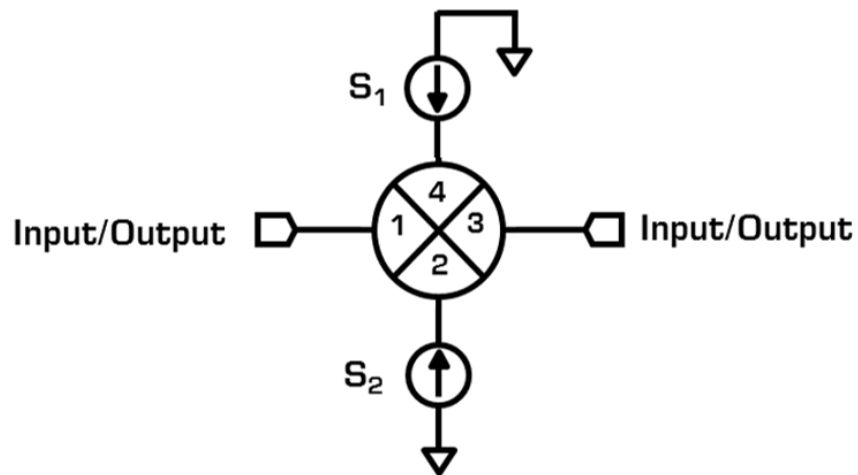
The diagram above shows an IQ mixer being used as a band shifter. Using an IQ mixer as a band shifter allows for sideband suppression. This is identical to using the IQ mixer as a single sideband up converter. However, the large signal input port is now the IF ports versus LO. Selection of the output tone is done through the orientation of the LO quadrature hybrid.

To use the mixer as a single sideband band shifter, input a low frequency large signal LO into the external LO quadrature hybrid. Input the high frequency small signal IF signal and take the high frequency RF output. Select the upper sideband (i.e., suppress the lower sideband) by connecting the I port to the 90° port of the IF quadrature hybrid and connect the Q port to the 0° port of the LO quadrature hybrid. Select the lower sideband (i.e., suppress the upper sideband) by connecting the I port to the 0° port of the LO quadrature hybrid and connect the Q port to the 90° port of the LO quadrature hybrid.

Using this input scheme requires careful accounting of which input signal is injected which port. Injecting a signal into any port which does not support the correct band will lead to a degraded or no output response. Abide by the maximum DC current input into the I and Q ports of the mixer or otherwise irreversible damage to the mixer will occur.

The limiting factor in use of the mixer as an image reject band shifter is in the bandwidth of the external LO quadrature hybrid and bandwidth of the I and Q ports.

Vector Modulator



Die Mounting Recommendations

Mounting and Bonding Recommendations

Marki MMICs should be attached directly to a ground plane with conductive epoxy. The ground plane electrical impedance should be as low as practically possible. This will prevent resonances and permit the best possible electrical performance. Datasheet performance is only guaranteed in an environment with a low electrical impedance ground.

Mounting

To epoxy the chip, apply a minimum amount of conductive epoxy to the mounting surface so that a thin epoxy fillet is observed around the perimeter of the chip. Cure epoxy according to manufacturer instructions.

Wire Bonding

Ball or wedge bond with 0.025 mm (1 mil) diameter pure gold wire. Thermosonic wirebonding with a nominal stage temperature of 150 °C and a ball bonding force of 40 to 50 grams or wedge bonding force of 18 to 22 grams is recommended. Use the minimum level of ultrasonic energy to achieve reliable wirebonds. Wirebonds should be started on the chip and terminated on the package or substrate. All bonds should be as short as possible <0.31 mm (12 mils).

Circuit Considerations

50 Ω transmission lines should be used for all high frequency connections in and out of the chip. Wirebonds should be kept as short as possible, with multiple wirebonds recommended for higher frequency connections to reduce parasitic inductance. In circumstances where the chip is more than .001" thinner than the substrate, a heat spreading spacer tab is optional to further reduce bondwire length and parasitic inductance.

Handling Precautions

General Handling

Chips should be handled with care using tweezers or a vacuum collet. Users should take precautions to protect chips from direct human contact that can deposit contaminants, like perspiration and skin oils on any of the chip's surfaces.

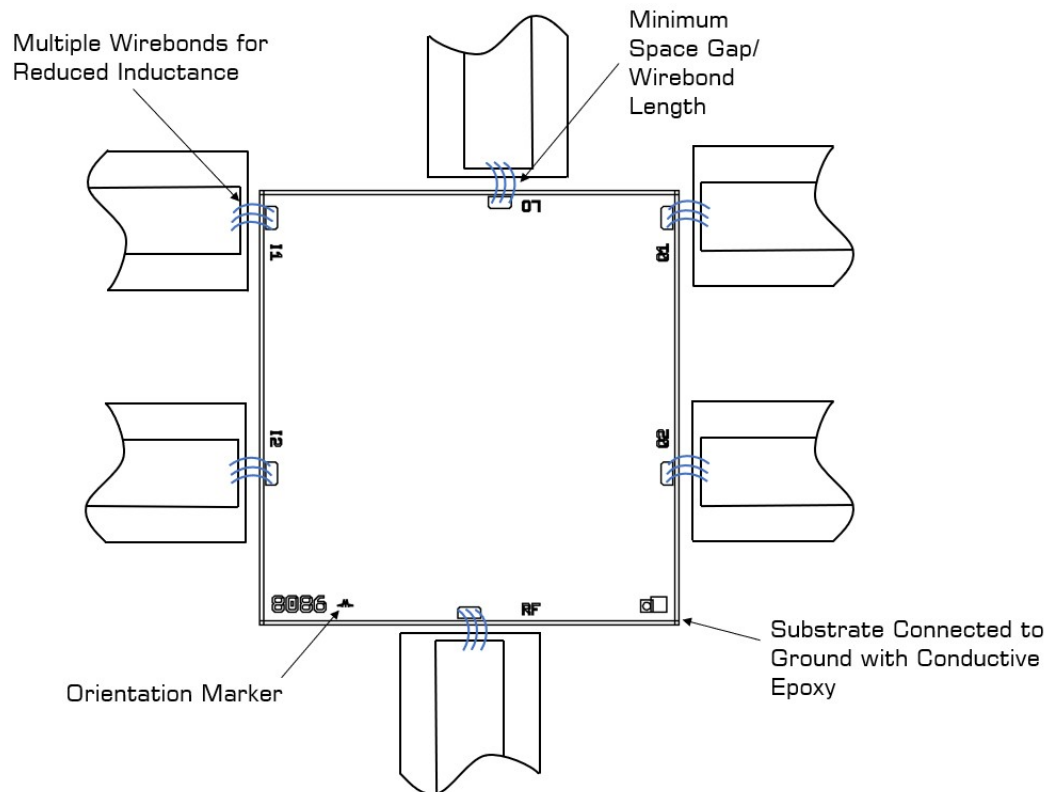
Static Sensitivity

GaAs MMIC devices are sensitive to ESD and should be handled, assembled, tested, and transported only in static protected environments.

Cleaning and Storage

Do not attempt to clean the chip with a liquid cleaning system or expose the bare chips to liquid. Once the ESD sensitive bags the chips are stored in are opened, chips should be stored in a dry nitrogen atmosphere.

Bonding Diagram

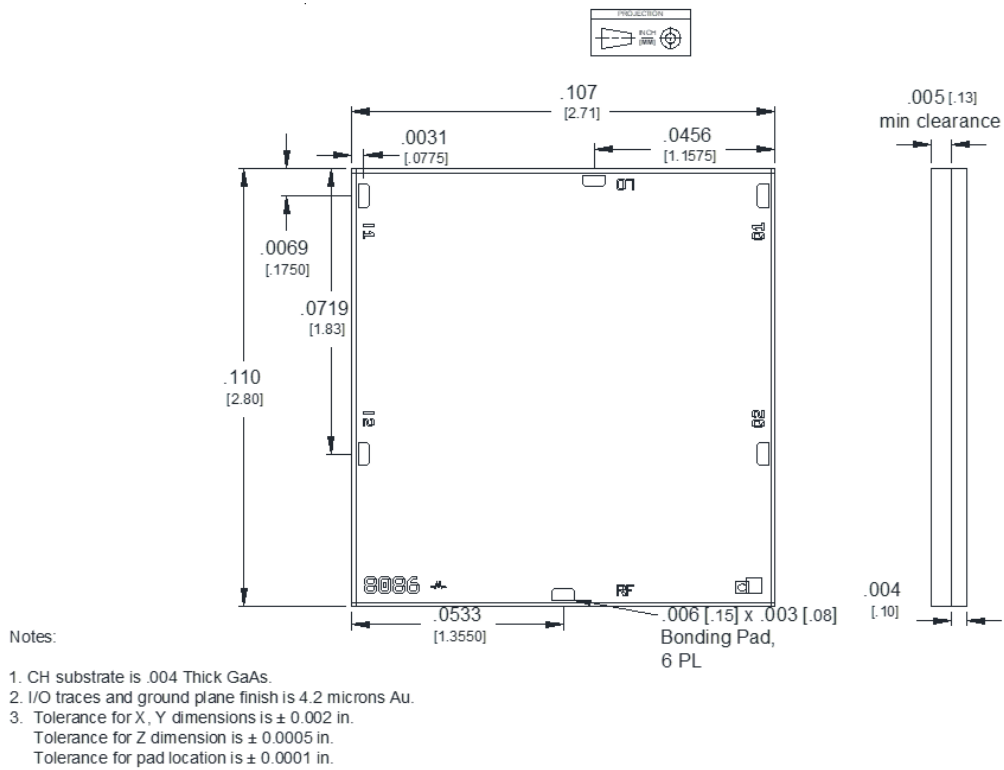


MMIQ-30120HCH-2

GaAs MMIC mmWave Differential IF IQ Mixer

Mechanical Data

Outline Drawing



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